Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-520-1823

Inclosure Materi	al:
Glass	
Overall Length:	
0.300 inches	
Terminal Length	: :
1.000 inches	
Overall Diamete	r:
Between 0.092 in	ches and 0.104 inches
Joint Electronic	Device Engineering Council/jedec/case Outline Designation:
Do-7	
Mounting Metho	d:
Terminal	
Features Provid	ed:
Hermetically seal	ed case
Semiconductor	Material:
Silicon	
Voltage Rating I	n Volts Per Characteristic:
100.0 forward vo	Itage, peak
Current Rating F	Per Characteristic:
4.73 milliamperes	s source cutoff current pascal
Power Rating Pe	er Characteristic:
600.0 milliwatts s	mall-signal input power, common-collector absolute
Maximum Opera	ting Tempurature Per Measurement Point:
200.0 degrees ce	Isius junction
Test Data Docur	nent:
96214-535985 sp	ecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification forma
excludes comme	rcial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental
and performance	requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	nd Quantity:
2 uninsulated wire	e lead
Shelf Life:	
N/a	
Unit Of Measure	:
 Demilitarization:	
No	
Fiig:	